# DTA125T series

PNP -100mA -50V Digital Transistors (Bias Resistor Built-in Transistors)

Datasheet

Parameter	Value
$V_{CEO}$	-50V
I <sub>C</sub>	-100mA
$R_1$	200kΩ

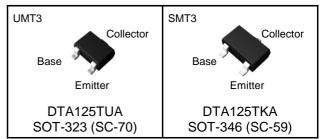
Features

- 1) Built-In Biasing Resistors
- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- 3) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of completely eliminating parasitic effects.
- 4) Only the on/off conditions need to be set for operation, making the circuit design easy.
- 5) Complementary NPN Types :DTC125T series
- 6) Lead Free/RoHS Compliant.

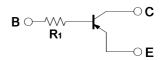
## Application

Switching circuit, Inverter circuit, Interface circuit, Driver circuit

#### Outline



#### •Inner circuit



#### Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
DTA125TUA	UMT3	2021	T106	180	8	3,000	9A
DTA125TKA	SMT3	2928	T146	180	8	3,000	9A

# ● **Absolute maximum ratings** (Ta = 25°C)

Parameter	Symbol	Values	Unit
Collector-base voltage	$V_{CBO}$	-50	V
Collector-emitter voltage	V <sub>CEO</sub>	-50	V
Emitter-base voltage	V <sub>EBO</sub>	<b>-</b> 5	V
Collector current	I <sub>C</sub>	-100	mA
Collector Power dissipation	P <sub>C</sub> <sup>*2</sup>	200	mW
Junction temperature	T <sub>j</sub>	150	°C
Range of storage temperature	T <sub>stg</sub>	−55 to +150	°C

# ●Electrical characteristics(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-base breakdown voltage	BV <sub>CBO</sub>	$I_C = -50\mu A$	-50	-	-	V
Collector-emitter breakdown voltage	BV <sub>CEO</sub>	$I_C = -1mA$	-50	-	-	V
Emitter-base breakdown voltage	$BV_{EBO}$	I <sub>E</sub> = -50μA	-5	-	1	V
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = -50V$	ı	ı	-0.5	μΑ
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = -4V$	ı	ı	-0.5	μΑ
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_{\rm C} / I_{\rm B} = -0.5 {\rm mA} / -0.05 {\rm mA}$	ı	ı	-0.3	V
DC current gain	h <sub>FE</sub>	$V_{CE}$ = -5V , $I_{C}$ = -1mA ,	100	250	600	-
Input resistance	R <sub>1</sub>	-	140	200	260	kΩ
Transition frequency	f <sub>T</sub> *1	$V_{CE} = -10V, I_{E} = 5mA,$ f = 100MHz		250	1	MHz

<sup>\*1</sup> Characteristics of built-in transistor

<sup>\*2</sup> Each terminal mounted on a reference footprint

#### ●Electrical characteristic curves(Ta = 25°C)

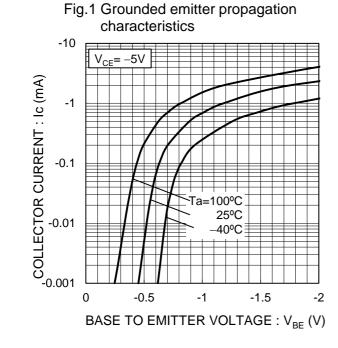


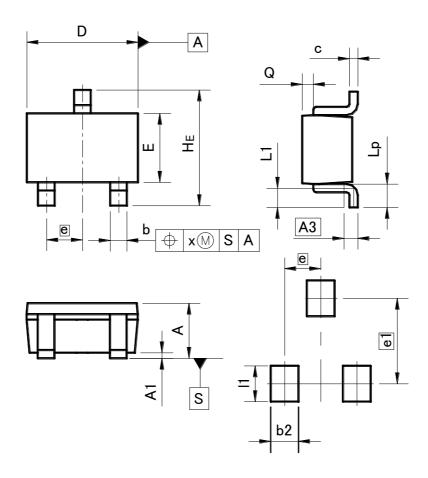
Fig.2 Grounded emitter output characteristics  $I_B =$ -20 100µA Ta=25°C -90µA COLLECTOR CURRENT : I<sub>C</sub> (mA) -80µA -15 -70µA -60µA -10 -50µA -40µA -5 -30µA –20µA 0 0A 0 -2 -6 -8 -10 **COLLECTOR TO EMITTER** VOLTAGE: V<sub>CF</sub> (V)

vs. Collector Current I<sub>C</sub>/I<sub>B</sub>=10/1 500m **COLLECTOR SATURATION** 200m Ta=100°C VOLTAGE: V<sub>CE</sub>(sat) (V) Ta=25°C 100m 50m Ta= -40°C 20m 10m 5m 2m 1m  $50\mu$   $100\mu$   $200\mu$   $500\mu$  1m 2m 10μ 20μ 10m COLLECTOR CURRENT : I<sub>C</sub> (mA)

Fig.4 Collector-emitter saturation voltage

# ●Dimensions (Unit:mm)

# UMT3



### **Patterm of terminal position areas**

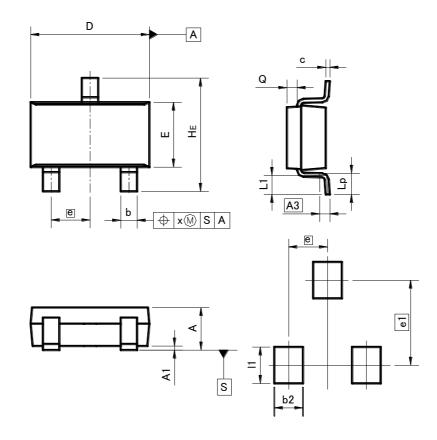
DIM	MILIM	MILIMETERS		HES
DIIVI	MIN	MAX	MIN	MAX
Α	0.80	1.00	0.031	0.039
A1	0.00	0.10	0	0.004
A3	0.3	25	0.0	01
b	0.15	0.30	0.006	0.012
С	0.10	0.20	0.004	0.008
D	1.90	2.10	0.075	0.083
E	1.15	1.35	0.045	0.053
е	0.0	65	0.0	03
HE	2.00	2.20	0.079	0.087
L1	0.20	0.50	0.008	0.02
Lp	0.25	0.55	0.01	0.022
Q	0.10	0.30	0.004	0.012
х	_	0.10		0.004

DIM	MILIMETERS		INCHES	
DIIVI	MIN MAX		MIN	MAX
e1	1.55		0.06	
b2	- 0.50		-	0.02
l1	-	0.65	-	0.026

Dimension in mm/inches

# ●Dimensions (Unit:mm)

# SMT3



## Patterm of terminal position areas

DIM	MILIMETERS		INCHES		
DIN	MIN	MAX	MIN	MAX	
Α	1.00	1.30	ı	0.051	
A1	0.00	0.10	0	0.004	
A3	0.2	25	0.0	01	
b	0.35	0.50	0.014	0.02	
С	0.09	0.25	0.004	0.01	
D	2.80	3.00	0.11	0.118	
E	1.50	1.80	0.059	0.071	
е	0.95		0.04		
HE	2.60	3.00	0.102	0.118	
L1	0.30	0.60	0.012	0.024	
Lp	0.40	0.70	0.016	0.028	
Q	0.20	0.30	0.008	0.012	
х		0.10	_	0.004	
У	_	0.10	_	0.004	

DIM	MILIMETERS		INCHES	
DIM	MIN MAX		MIN	MAX
e1	2.10		0.08	
b2		0.60	-	0.024
11	_	0.90	-	0.035

Dimension in mm/inches

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